

High-Voltage Protect USB 2.0 DPDT Switch

General Description

ET7429 is a Hi-Speed (up to 480Mbps) USB dual SPDT switch with over-voltage protection. It operates over a 2.7V to 5.5V supply range with over-voltage fault protection up to 20V. The device features independent control bits for each switch pair and an on/off enable ($\overline{\text{EN}}$) for shutdown mode. Additional features include low switch on resistance and capacitance along with a fault flag ($\overline{\text{FLAG}}$) to alert the system processor to over-voltage fault events.

ET7429 has low power consumption and is available in an ultra-small CSP12 1.15mm×1.55mm package making it an ideal solution for USB interface switching and protection in mobile applications.

Features

- Operating Range from 2.7V to 5.5V
- For USB D+/D- Hi-Speed or SBU 1/2 Signals
- Reverse Blocking Back-to-back MOSFETs
- >1GHz -3dB Bandwidth
- Low 6Ω Switch On-Resistance
- Typical 6.0pF Switch On-Capacitance
- Over-voltage Protection Up to +22V
- $\overline{\text{FLAG}}$ Open Drain Output Over-voltage Indicator
- $\overline{\text{EN}}$ to Disable Switch Output
- -40°C to +85°C Temperature Range
- MSL1
- Part No. and Package

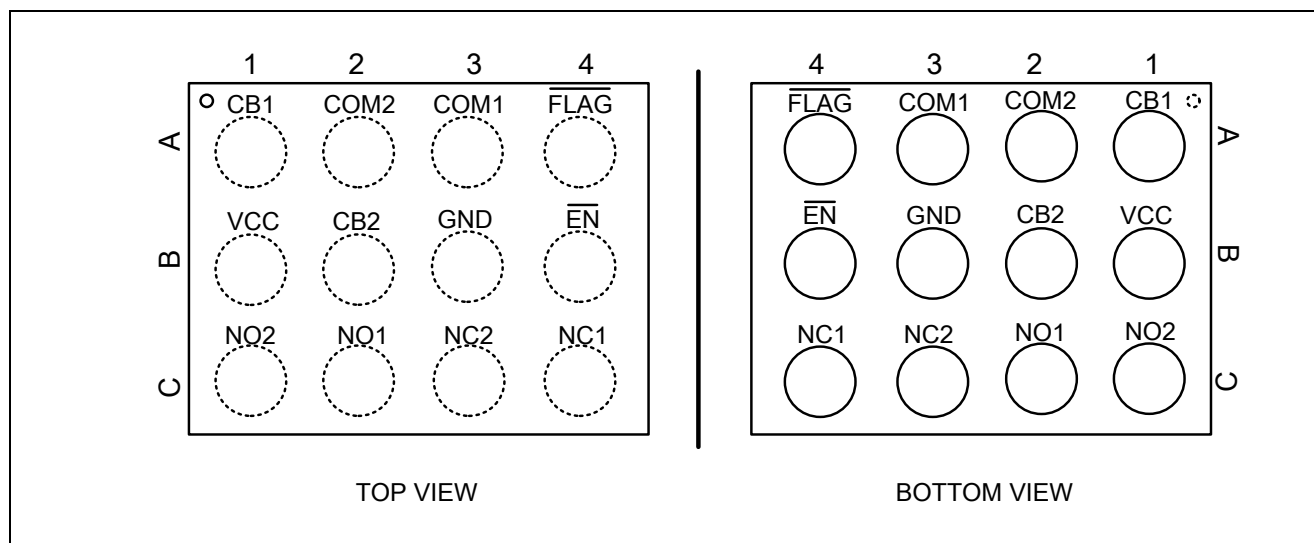
Part No.	Package
ET7429	CSP12(1.15mm × 1.55mm, Ball pitch = 0.4mm)

Applications

- Smartphones
- USB Type-C
- Mobile Internet Devices
- Tablet Computers
- Peripheral

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Pin Configuration



Pin Function

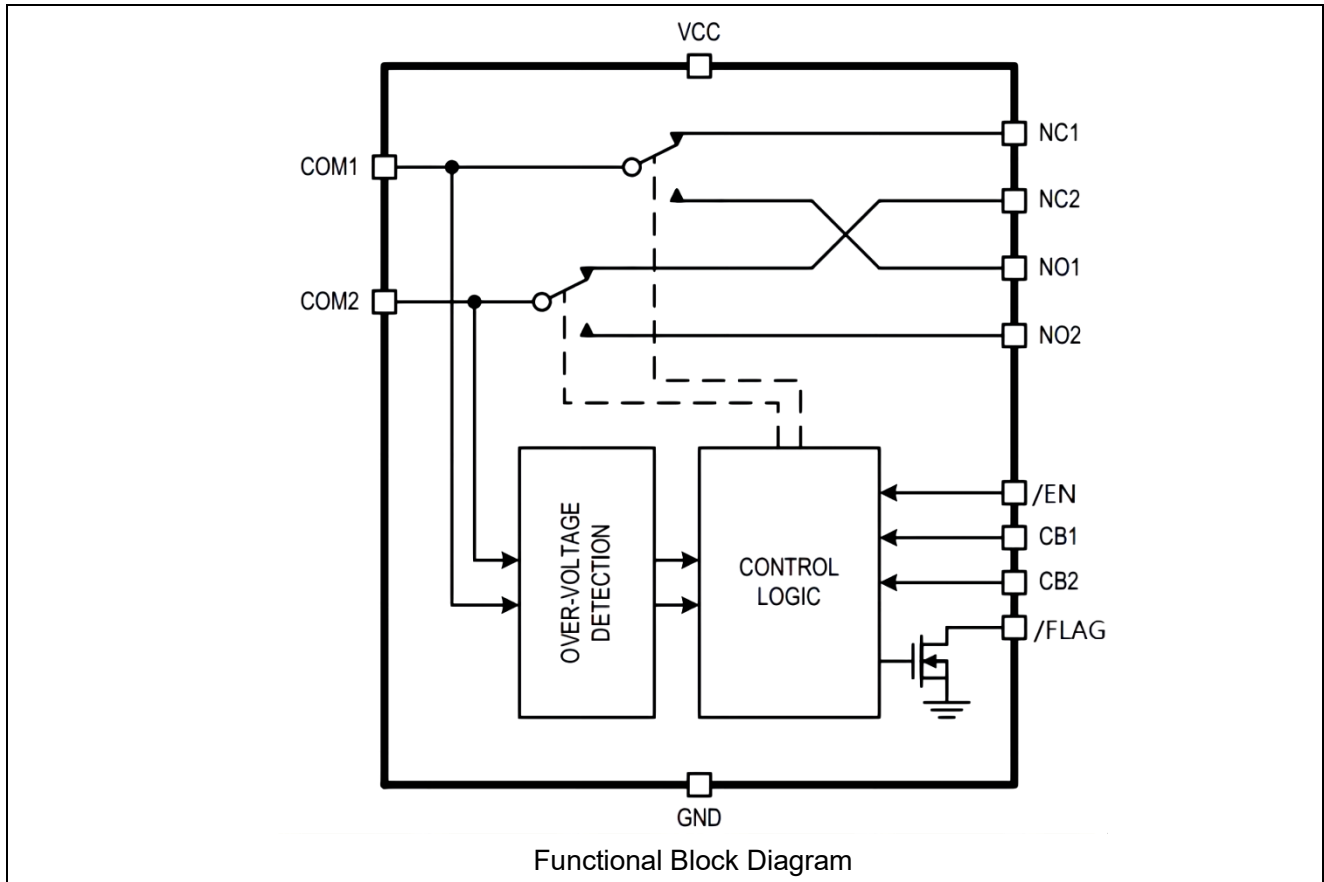
Pin	Name	Description
A1	CB1	Digital Control Input 1
A2	COM2	Common Terminal for I/O Switch 1 (Connect to D+, D-, SBU1 or SBU2)
A3	COM1	Common Terminal for I/O Switch 2 (Connect to D+, D-, SBU1 or SBU2)
A4	FLAG	Active low fault flag output signal to alert fault event
B1	VCC	Input Supply Voltage input pin
B2	CB2	Digital Control Input 2
B3	GND	Ground pin
B4	EN	Active low enable input pin. Drive EN to a logic high level to disable the device and place switches to a high impedance state.
C1	NO2	Normally Open Terminal for USB I/O Switch 2
C2	NO1	Normally Open Terminal for USB I/O Switch 1
C3	NC2	Normally Open Terminal for USB I/O Switch 2
C4	NC1	Normally Open Terminal for USB I/O Switch 1

Truth Table

EN	CB1	CB2	COM1 Connection	COM2 Connection
H	x	x	High-Z	High-Z
L	L	L	COM1 to NC1	COM2 to NC2
L	L	H	COM1 to NC1	COM2 to NO2
L	H	L	COM1 to NO1	COM2 to NC2
L	H	H	COM1 to NO1	COM2 to NO2

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Block Diagram



Absolute Maximum Ratings

Symbol	Pins	Parameter		Value	Unit
V _{CC}	VCC	Positive DC Supply Voltage		-0.5 to +6.0	V
V _{IS}	NC1/NO1, NC2/NO2	Analog Signal Voltage		-0.3 to +6.0	V
	COM1, COM2			-0.5 to +20	
V _{IN}	CB1, CB2, $\overline{\text{EN}}$	Control Input Voltage		-0.5 to +6.0	V
T _{STG}		Storage Temperature		-65 to +150	°C
ESD	All Pins	Electrostatic Discharge Capability	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	±2.5	KV
			Charged Device Model, JESD22-C101	±2.0	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

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Recommended Operating Conditions

Symbol	Pins	Parameter	Min	Max	Unit
V _{CC}	VCC	Positive DC Supply Voltage	2.7	5.5	V
V _{I/O}	NC1, NO1, NC2, NO2	Analog Input/output Voltage	0	3.6	V
	COM1, COM2		0	18	
V _{IN}	$\overline{\text{EN}}$, CB1, CB2	Digital Select Input Voltage	0	5.5	V
V _O	$\overline{\text{FLAG}}$	Digital Output Voltage	0	5.5	V
I _{I/O}	COM1, COM2, NC1, NO1, NC2, NO2	Analog Input/output Port Continuous Current	-50	50	mA
I _{OL}		Digital Output Current		1	mA
T _A		Operating Temperature Range	-40	+85	°C

Minimum and maximum values are guaranteed through test or design across the Recommended Operating Conditions, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.

DC Electrical Characteristics

Digital Characteristics (Typical: T_A = 25°C, V_{CC} = 3.3 V)

Symbol	Pin Name	Parameter	Test Conditions	V _{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
V _{IH}	$\overline{\text{EN}}$, CB1, CB2	Control Input High Voltage		2.7~5.5	1.2	-	-	V
V _{IL}	$\overline{\text{EN}}$, CB1, CB2	Control Input Low Voltage		2.7~5.5	-		0.4	V
V _{OL}	$\overline{\text{FLAG}}$	Output Logic Low	I _{OL} =1mA	2.7~5.5			0.5	V
I _{IH}	$\overline{\text{EN}}$, CB1, CB2	Input High leakage Current	$\overline{\text{EN}}$, CB1, CB2=1.8V	2.7~5.5	-1	0.5	5	uA
I _{IL}	$\overline{\text{EN}}$, CB1, CB2	Input Low Leakage Current	$\overline{\text{EN}}$, CB1, CB2=0V	2.7~5.5	-1	±0.1	5	uA
R _{PD}	$\overline{\text{EN}}$, CB1, CB2	Internal Pull-down Resistor on Digital Input Pins				5		MΩ

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Supply and Leakage Current Characteristics (Typical: $T_A = 25^\circ\text{C}$, $V_{CC} = 3.3\text{ V}$)

Symbol	Pin Name	Parameter	Test Conditions	$V_{CC}(\text{V})$	-40°C to +85°C			Unit
					Min	Typ	Max	
I_{CC}	V_{CC}	Active Supply Current	$\overline{EN}=0\text{V}$ $CB1, CB2=0\text{V}$ or V_{CC} $0\text{V} < V_{I/O} < 3.6\text{V}$	5.5		30		μA
I_{CC_PD}	V_{CC}	Standby Powered Down Supply Current	$\overline{EN}=V_{CC}$ $CB1, CB2=0\text{V}$ or V_{CC} or $CB1, CB2=V_{CC}$	5.5		2.2	10	μA
I_{ON}	$V_{I/O}$	ON Leakage Current	$V_{COMn}=0\text{V}$ or 3.6V $V_{Nn}=\text{high-Z}$, Figure 3			1		μA
I_{OFF}	$V_{I/O}$	I/O pin OFF Leakage Current	$V_{COMn}=0\text{V}$ or 3.6V $V_{CC}=2.7\text{V}$ to 5.5V $V_{Nn}=3.6\text{V}$ or 0V , Figure 2			1		μA
			$V_{COMn}=20\text{V}$, $V_{CC}=2.7\text{V}$ to 5.5V $V_{Nn}=0\text{V}$, Figure 2			15		

Protection Characteristics

Symbol	Parameter	Test Conditions	-40°C to +85°C			Unit
			Min	Typ	Max	
V_{OVP_TH}	OVP positive threshold		4.5	4.8	5.2	V
V_{OVP_HYST}	OVP threshold hysteresis			250		mV
V_{CLAMP_V}	Maximum voltage to appear on NCn and Non pins during OVP scenario ⁽¹⁾	$V_{COMn}=0$ to 18V t_{RISE} and $t_{FALL}(10\% \text{ to } 90\%)=100\text{ns}$ $R_L=50\Omega$, Switch on or off, $\overline{EN}=0\text{V}$	0		9.0	V
t_{EN_OVP}	OVP enable time ⁽¹⁾	$R_{PU}=10\text{K}\Omega$ to V_{CC} ($\overline{FLAG}$) $C_L=35\text{pF}$, Figure 9		60		ns
t_{REC_OVP}	OVP recovery time ⁽¹⁾	$R_{PU}=10\text{K}\Omega$ to V_{CC} ($\overline{FLAG}$) $C_L=35\text{pF}$, Figure 9		0.4		μs
t_{OFF_RES}	Switch turn-off response time ⁽¹⁾	$R_L=50\Omega$, No C_L , $V_{COM} > V_{OVP_TH}$ to V_{NX} stop rising		60		ns

High Speed on Resistance (Typical: $T_A = 25^\circ\text{C}$, $V_{CC} = 3.3\text{ V}$)

Symbol	Parameter	Test Conditions	$V_{CC}(\text{V})$	-40°C to +85°C			Unit
				Min	Typ	Max	
R_{ON}	On-Resistance	$V_{IO} = 0.4\text{V}$, $I_{SINK}=8\text{mA}$, Figure 1	3.3		6.0	9.0	Ω
R_{FLAT}	On-Resistance Flatness	$V_{IO} = 0\text{V}$ to 0.4V , $I_{SINK}=8\text{mA}$, Figure 1	3.3		0.05	0.4	Ω
ΔR_{ON}	On-Resistance Match between Channels	$V_{IO} = 0.4\text{V}$, $I_{SINK}=8\text{mA}$, Figure 1	3.3		0.1	0.3	Ω

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AC Electrical Characteristics

Timing/Frequency (Typical: $T_A = 25^\circ\text{C}$, $V_{CC} = 3.3\text{V}$, $R_L = 50\Omega$, $C_L = 5\text{pF}$, $f = 1\text{MHz}$)

Symbol	Parameter	Test Conditions	$V_{CC}(\text{V})$	-40°C to +85°C			Unit
				Min	Typ	Max	
t_{SWITCH}	Switch Time between Channel (CB1,CB2 to Output)	$V_{\text{COMn}}=0.8\text{V}$, $R_L=50\Omega$ $C_L=5\text{pF}$, Figure 4	2.7~5.5		5.5		us
t_{ON}	Device turn on time ($\overline{\text{EN}}$ to Output)	$V_{\text{COMn}}=0.8\text{V}$, $R_L=50\Omega$ $C_L=5\text{pF}$, Figure 5	2.7~5.5		120	250	us
t_{OFF}	Device Turn Off Time ⁽¹⁾ ($\overline{\text{EN}}$ to Output)	$V_{\text{COMn}}=0.8\text{V}$, $R_L=50\Omega$ $C_L=5\text{pF}$, Figure 5	2.7~5.5		0.015	0.5	us
$t_{\text{SK(P)}}$	Skew of Opposite Transitions of Same Output ⁽¹⁾ (Between COM1 and COM2)	$V_{\text{COMn}}=0.4\text{V}$, $R_L=50\Omega$ $C_L=1\text{pF}$, Figure 11	2.7~5.5		9	50	ps
t_{PD}	Propagation Delay ⁽¹⁾	$V_{\text{COMn}}=0.4\text{V}$, $R_L=50\Omega$ $C_L=5\text{pF}$, Figure 10	2.7~5.5		130	180	ps
BW	-3dB Bandwidth ⁽¹⁾	Switch on, $R_L=50\Omega$, Figure 8	4.2		1.0		GHz

Isolation (Typical: $T_A = 25^\circ\text{C}$, $V_{CC} = 3.3\text{V}$, $R_L = 50\Omega$, $C_L = 5\text{pF}$, $f = 1\text{MHz}$)

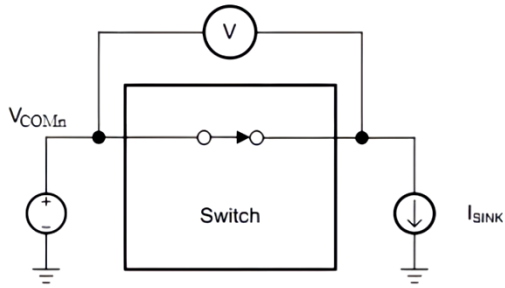
Symbol	Pin Name	Parameter	Test Conditions	$V_{CC}(\text{V})$	-40°C to +85°C			Unit
					Min	Typ	Max	
O_{IRR}	NO/NC	OFF-Isolation ⁽¹⁾ (Figure 6)	Switch off, $R_L=50\Omega$ $C_L=5\text{pF}$, $f=100\text{kHz}$	2.7~5.5		-90		dB
			Switch off, $R_L=50\Omega$ $C_L=5\text{pF}$, $f=240\text{MHz}$	2.7~5.5		-28		dB
X_{TALK}	COM1/ COM2	Non-Adjacent Channel Crosstalk ⁽¹⁾	Switch on, $R_L=50\Omega$ $C_L=5\text{pF}$, $f=100\text{kHz}$ Figure 7	2.7~5.5		-90		dB

Capacitance (Typical: $T_A = 25^\circ\text{C}$, $V_{CC} = 3.3\text{V}$)

Symbol	Pin Name	Parameter	Test Conditions	$V_{CC}(\text{V})$	-40°C to +85°C			Unit
					Min	Typ	Max	
C_{I}	$\overline{\text{EN}}$ CB1, CB2	Digital Input Capacitance ⁽¹⁾	$f=1\text{MHz}$	2.7-5.5		3.4		pF
C_{ON}	I/O	I/O Pins ON Capacitance ⁽¹⁾	$\overline{\text{EN}}=0\text{V}$ $f=1\text{MHz}$	2.7-5.5		6.0		pF
C_{OFF}	COM1 COM2	COM1 COM2 Off Capacitance ⁽¹⁾	Switch off $\overline{\text{EN}}=V_{CC}$, $f=1\text{MHz}$	2.7-5.5		5.5		pF
	NC1 NO1 NC2 NO2	NC1 NO1 NC2 NO2 Off Capacitance ⁽¹⁾	Switch off $\overline{\text{EN}}=V_{CC}$, $f=1\text{MHz}$	2.7-5.5		2.2		pF

Note1: Guaranteed by design.

Test Reference Circuit



Channel ON, $R_{ON} = V/I_{SINK}$

Figure 1. ON-State Resistance (R_{ON})

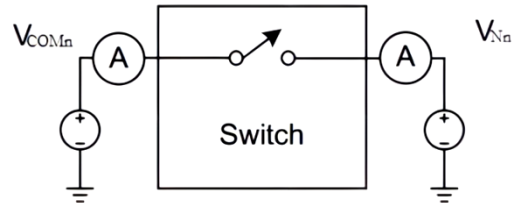


Figure 2. Off Leakage

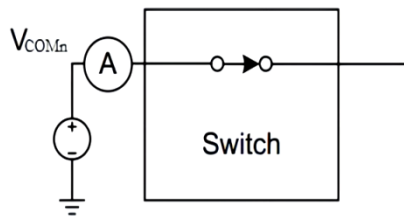
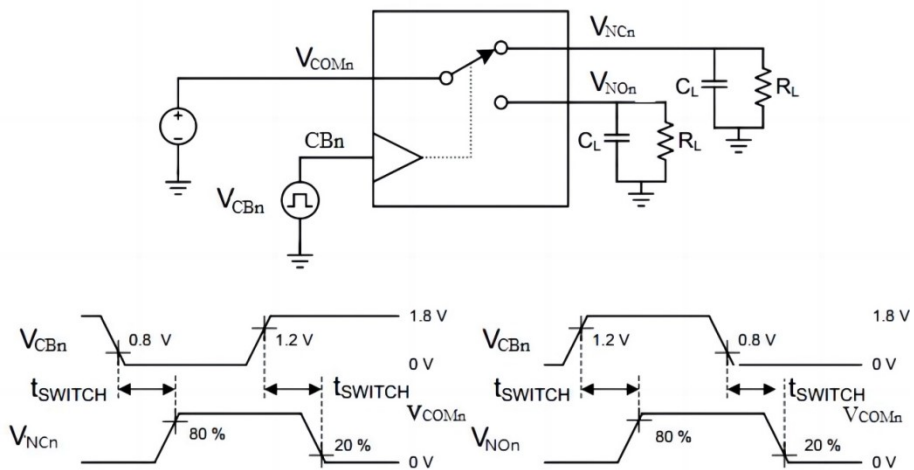


Figure 3. On Leakage

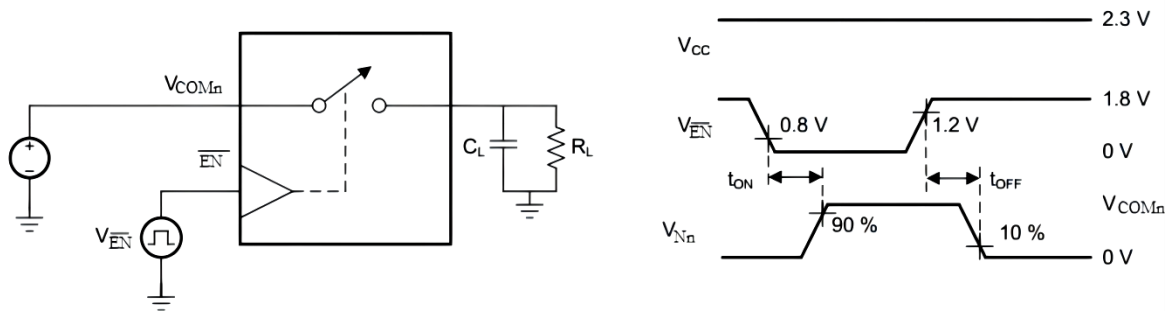


(1) All input pulses are supplied by generators having the following characteristics:

$P_{RR} \leq 10\text{MHz}$, $Z_0 = 50\Omega$, $t_r < 500\text{ps}$, $t_f < 500\text{ps}$

(2) C_L include probe and jig capacitance

Figure 4. t_{SWITCH} Timing



- (1) All input pulses are supplied by generators having the following characteristics:
 $P_{RR} \leq 10 \text{ MHz}$, $Z_0 = 50 \Omega$, $t_r < 500 \text{ ps}$, $t_f < 500 \text{ ps}$
- (2) C_L include probe and jig capacitance

Figure 5. t_{ON} t_{OFF} for $\overline{EN}$

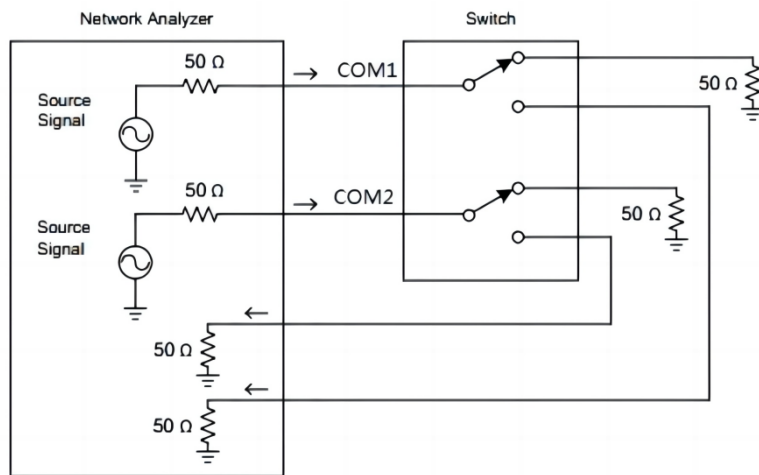


Figure 6. Off Isolation

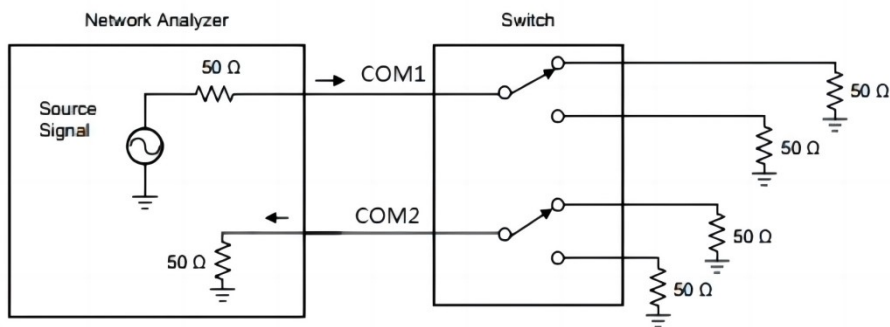


Figure 7. Cross Talk

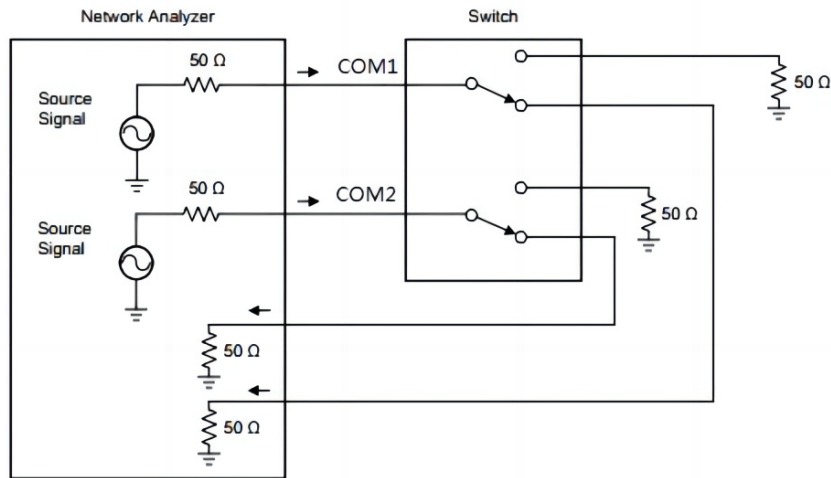


Figure 8. BW

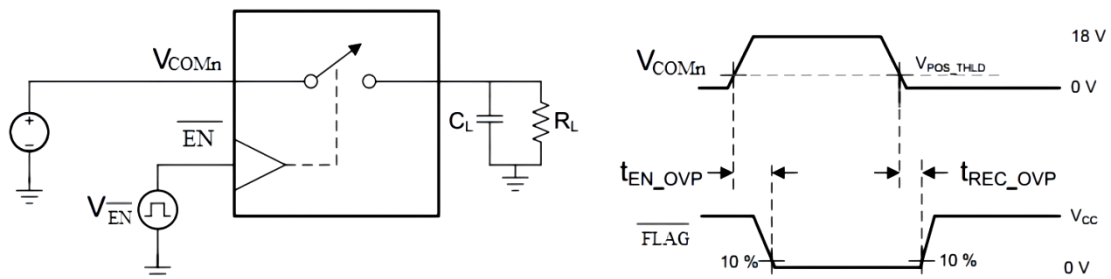
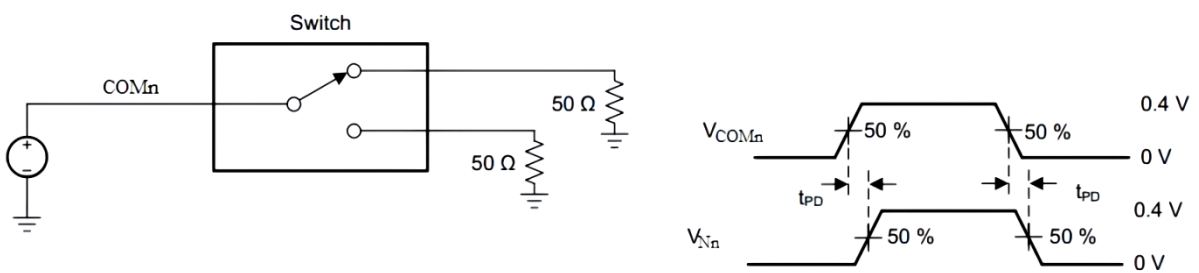


Figure 9. t_{EN_OVP} and t_{DIS_OVP} Timing Diagram



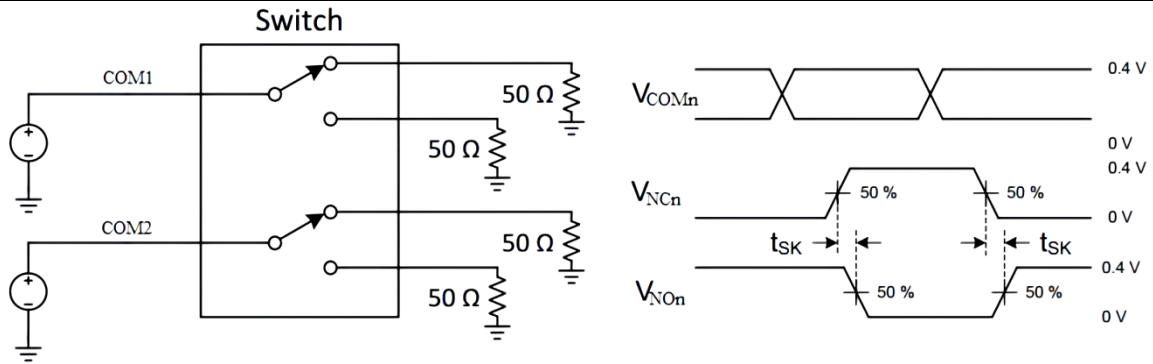
(1) All input pulses are supplied by generators having the following characteristics:

$P_{RR} \leq 10\text{MHz}$, $Z_0 = 50\Omega$, $t_r < 500\text{ps}$, $t_f < 500\text{ps}$

(2) C_L include probe and jig capacitance

Figure 10. t_{PD}

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(1) All input pulses are supplied by generators having the following characteristics:

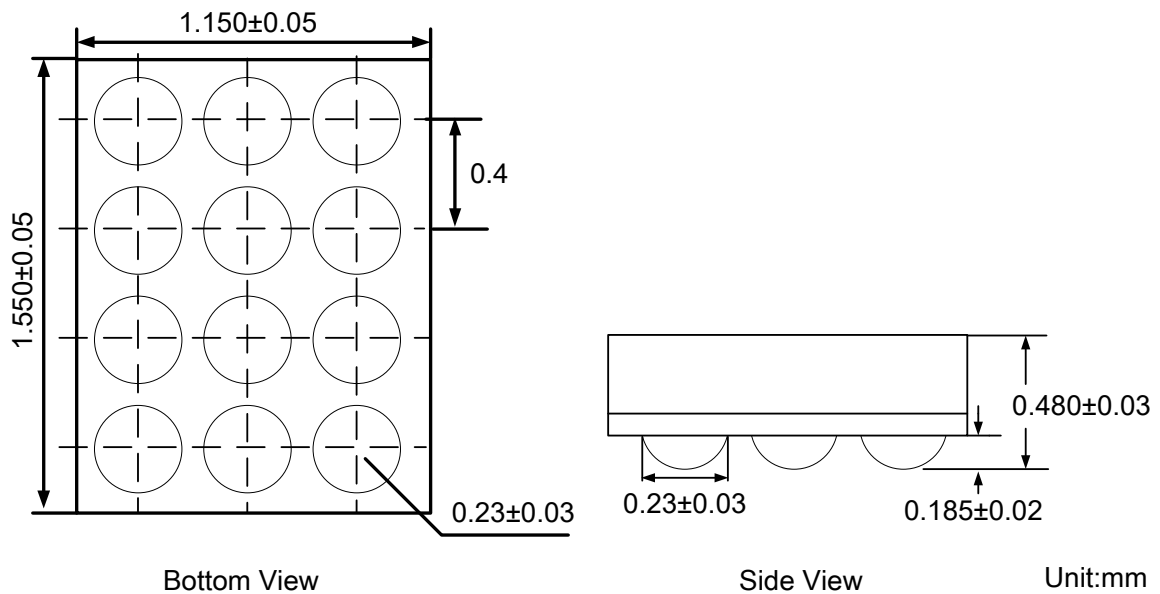
$P_{RR} \leq 10\text{MHz}$, $Z_O = 50\Omega$, $t_r < 500\text{ps}$, $t_f < 500\text{ps}$

(2) C_L include probe and jig capacitance

Figure 11. t_{SK}

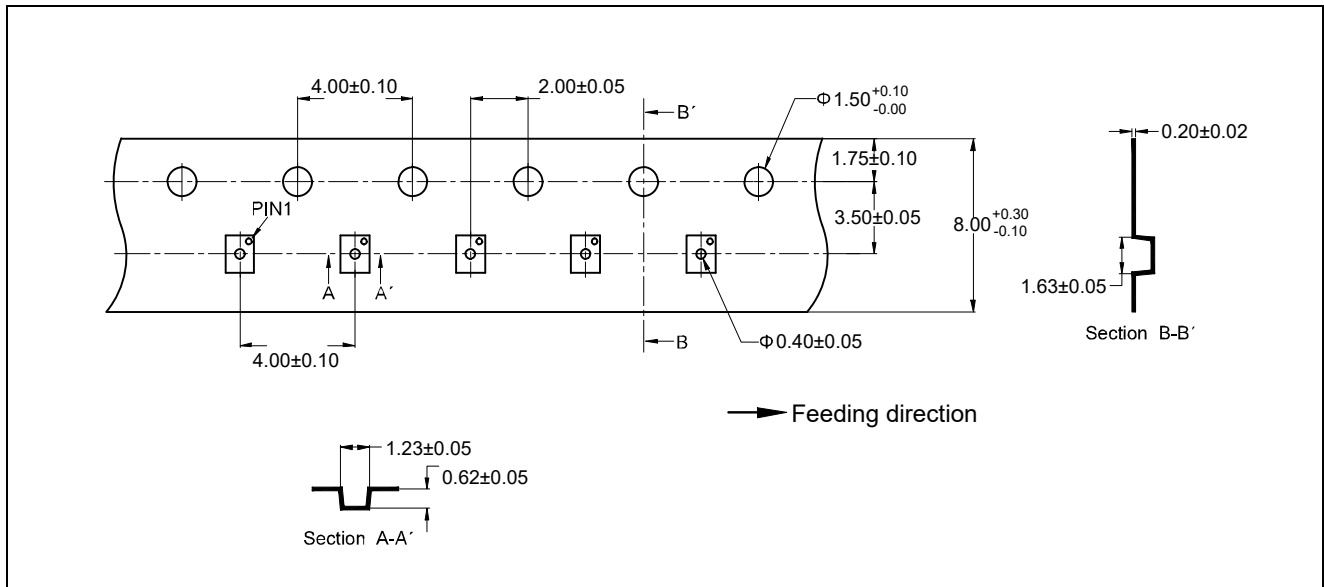
Package Dimension

CSP12

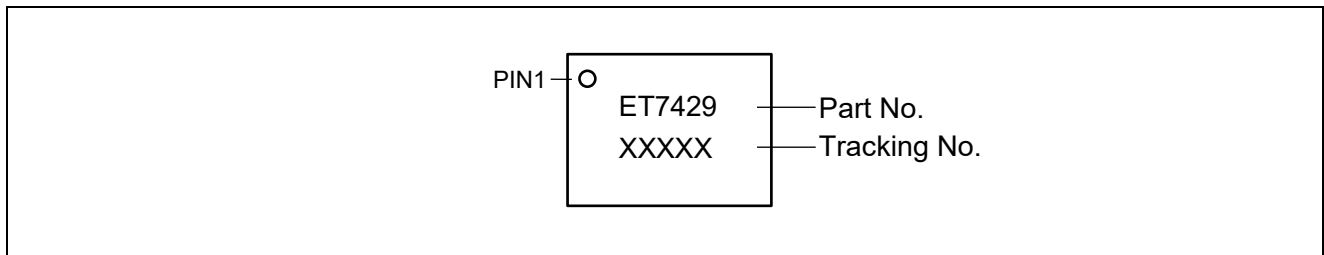


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Tape



Marking



Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2019-12-20	Released Version	Luh	Luh	Zhuji
1.1	2020-03-13	Documents check and formalize	Shib	Shib	Liuji
1.2	2020-03-17	Add MSL level	Luh	Luh	Zhuji
1.3	2020-05-11	Update tape information	Luh	Luh	Liuji
1.4	2023-4-2	Update Typeset	Shibo	Luh	Liuji
1.5	2023-8-15	Package to lossless format	Shibo		
1.6	2023-9-1	Correct packaging height	Shibo	Luh	Liuji